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## WHAT IS CLAIMED IS:

A composition for sealing a semiconductor device having thermoplastic properties and a line expansion coefficient of  $6.0 \times 10^{-5}$  [1/°C] or less at a temperature of  $80^{\circ}$ C to  $130^{\circ}$ C.

- %. A composition for sealing a semiconductor device according to claim 1, wherein the line expansion coefficient  $4.75 \times 10^{-5}$  [1/°C] or less at a temperature of  $150^{\circ}$ C to  $200^{\circ}$ C.
- 3. A composition for sealing a semiconductor device according to claim 1, wherein a line expansion coefficient ratio between a flow direction and a normal direction of the flow direction is 0.55 or more.
  - 4. A composition for sealing a semiconductor device according to claim 1, wherein the composition has a bending strength after solidification is 74 MPa or more.
    - 5. A composition for sealing a semiconductor device according to claim 1, wherein an adhesion imparting agent is added to improve adhesion properties to another material by binding with a polar group.
    - 6. A composition for sealing a semiconductor device according to claim 1, further containing silica particles.
- 7. A composition for sealing a semiconductor device according to claim 1, further containing a fibrous material.

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- 8. A composition for sealing a semiconductor device according to claim 1, further containing a thermosetting resin material.
- 9. A composition for sealing a semiconductor device according to claim 1, wherein a product obtained by multiplying a value of a line expansion at 25 to  $80^{\circ}$ C plus a line expansion at  $80-125^{\circ}$ C after solidification, by a bending strength is 25 MPa or less.
  - 10. A semiconductor device comprising:
  - a semiconductor element;

a semiconductor resin composition for sealing the semiconductor element; and

a conducting material electrically connected to the semiconductor element one end of which is sealed with the semiconductor resin composition,

wherein the semiconductor sealing resin composition has thermoplastic properties and a thermal expansion coefficient is  $6.0 \times 10^{-5}$  [1/°C] or less at a temperature of 80 to 130°C.

- 11. A semiconductor device according to claim 10, wherein the semiconductor sealing resin composition has thermoplastic properties and a thermal expansion coefficient at 150 to 200°C is  $4.75 \times 10^{-5} [1/\degree\text{C}]$  or less.
- 25 12. A semiconductor device according to claim 10, wherein the semiconductor sealing resin composition has thermoplastic properties and a line expansion

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coefficient ratio between a flow direction and a normal direction of the flow direction is 0.55 or more.

- 13. A semiconductor device according to claim 10, wherein a bending strength of the semiconductor sealing resun composition after solidification is 74 MPa or more.
- 14. A semiconductor device according to claim 10, wherein an adhesion imparting agent is added the semiconductor sealing resin composition to improve adhesion properties to another material by binding with a polar group.
- 15. A semiconductor device according to claim 10, wherein the semiconductor sealing resin composition contains silica particles.
- 16. A semiconductor device according to claim 10, wherein the semiconductor sealing resin composition contains a fibrous material.
- 17. A semiconductor device according to claim 10, wherein the semiconductor sealing resin composition contains a thermosetting material.
- 18. A semiconductor device according to claim 10, wherein the semiconductor element is coated with polyimide.
- 19. A semiconductor device according to claims 10
  25 to 13, wherein the semiconductor sealing resin
  composition is thermoplastic and a product obtained by
  multiplying a value of a line expansion at 25 to 80°C

plus a line expansion at  $80-125^{\circ}$ C after solidification, by a bending strength is 25 MPa or less.

20. A method of manufacturing a semiconductor device comprising the steps of:

electrically connecting a semiconductor element and a conducting material; and

sealing the semiconductor element with a thermoplastic semiconductor sealing resin composition and a line expansion coefficient at 80 to  $130^{\circ}$ C is  $6.0 \times 10^{-5}$  [1/°C] or less.

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